

# International IOR Rectifier

## 30ETH06PbF

### Hyperfast Rectifier

#### Features

- Hyperfast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature
- Dual Diode Center Tap
- Lead-Free ("PbF" suffix)

$$t_{rr} = 28\text{ns typ.}$$

$$I_{F(AV)} = 30\text{Amp}$$

$$V_R = 600\text{V}$$

#### Description/ Applications

State of the art Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, Hyperfast recover time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC-DC section of SMPS, inverters or as freewheeling diodes.

The IR extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

#### Absolute Maximum Ratings

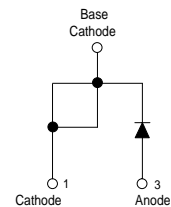
Parameters	Max	Units
$V_{RRM}$ Peak Repetitive Reverse Voltage	600	V
$I_{F(AV)}$ Average Rectifier Forward Current @ $T_C = 103^\circ\text{C}$	30	A
$I_{FSM}$ Non Repetitive Peak Surge Current @ $T_J = 25^\circ\text{C}$	200	
$T_J, T_{STG}$ Operating Junction and Storage Temperatures	- 65 to 175	$^\circ\text{C}$

#### Case Styles

30ETH06PbF



TO-220AC



**Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)**

Parameters	Min	Typ	Max	Units	Test Conditions
V <sub>BR</sub> , V <sub>F</sub> Breakdown Voltage, Blocking Voltage	600	-	-	V	I <sub>R</sub> = 100μA
V <sub>F</sub> Forward Voltage	-	2.0	2.6	V	I <sub>F</sub> = 30A, T <sub>J</sub> = 25°C
	-	1.34	1.75	V	I <sub>F</sub> = 30A, T <sub>J</sub> = 150°C
I <sub>R</sub> Reverse Leakage Current	-	0.3	50	μA	V <sub>R</sub> = V <sub>R</sub> Rated
	-	60	500	μA	T <sub>J</sub> = 150°C, V <sub>R</sub> = V <sub>R</sub> Rated
C <sub>T</sub> Junction Capacitance	-	33	-	pF	V <sub>R</sub> = 600V
L <sub>S</sub> Series Inductance	-	8.0	-	nH	Meas. lead to lead 5mm from package body

**Dynamic Recovery Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)**

Parameters	Min	Typ	Max	Units	Test Conditions	
t <sub>rr</sub> Reverse Recovery Time	-	28	35	ns	I <sub>F</sub> = 1.0A, di <sub>F</sub> /dt = 50A/μs, V <sub>R</sub> = 30V  I <sub>F</sub> = 30A V <sub>R</sub> = 200V di <sub>F</sub> /dt = 200A/μs	
	-	31	-			T <sub>J</sub> = 25°C
	-	77	-			T <sub>J</sub> = 125°C
I <sub>RRM</sub> Peak Recovery Current	-	3.5	-	A	T <sub>J</sub> = 25°C	
	-	7.7	-		T <sub>J</sub> = 125°C	
Q <sub>rr</sub> Reverse Recovery Charge	-	65	-	nC	T <sub>J</sub> = 25°C	
	-	-	345		T <sub>J</sub> = 125°C	

**Thermal - Mechanical Characteristics**

Parameters	Min	Typ	Max	Units
T <sub>J</sub> Max. Junction Temperature Range	- 65	-	175	°C
T <sub>Stg</sub> Max. Storage Temperature Range	- 65	-	175	
R <sub>thJC</sub> Thermal Resistance, Junction to Case Per Leg	-	0.7	1.1	°C/W
R <sub>thJA</sub> <sup>①</sup> Thermal Resistance, Junction to Ambient Per Leg	-	-	70	
R <sub>thCS</sub> <sup>②</sup> Thermal Resistance, Case to Heatsink	-	0.2	-	
Wt Weight	-	2.0	-	g
	-	0.07	-	(oz)
Mounting Torque	6.0	-	12	Kg-cm
	5.0	-	10	lbf.in
Case Style	TO-220AC			JEDEC
Marking Device	30ETH06			

① Typical Socket Mount

② Mounting Surface, Flat, Smooth and Greased

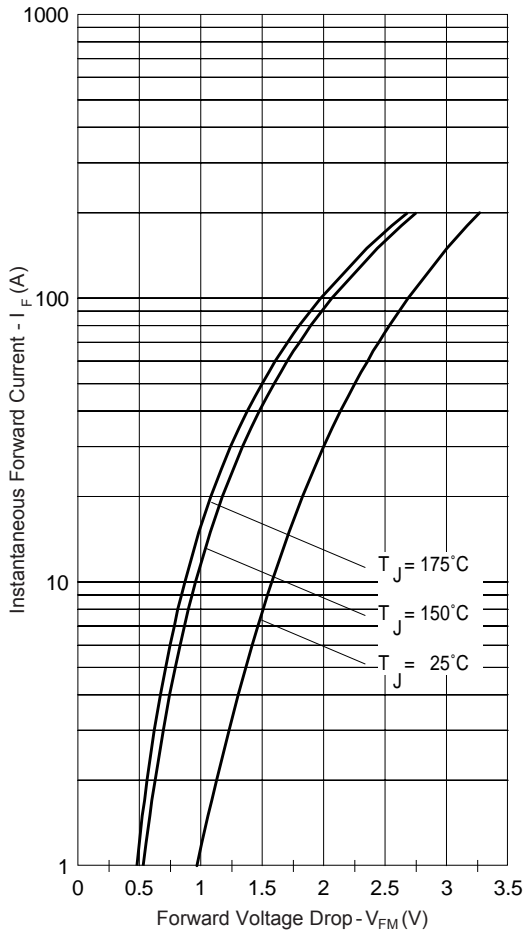


Fig. 1 - Typical Forward Voltage Drop Characteristics

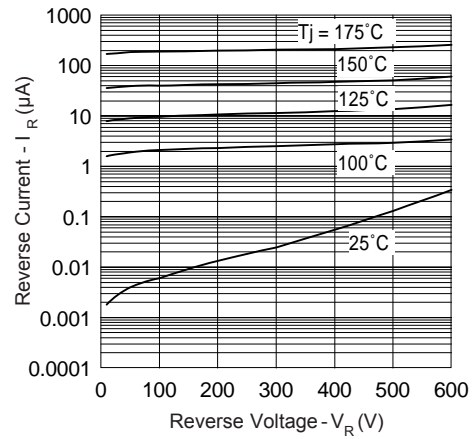


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

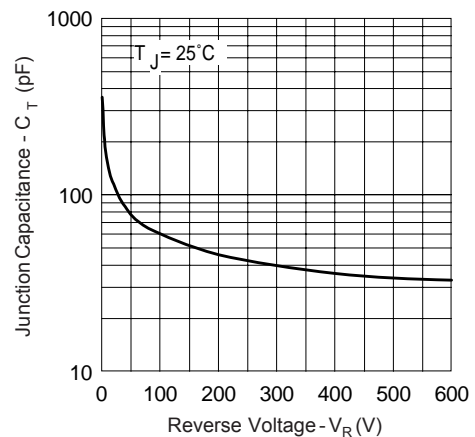


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

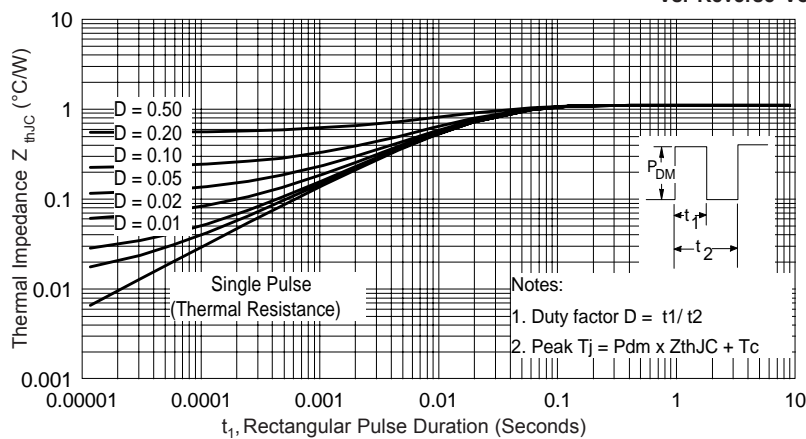
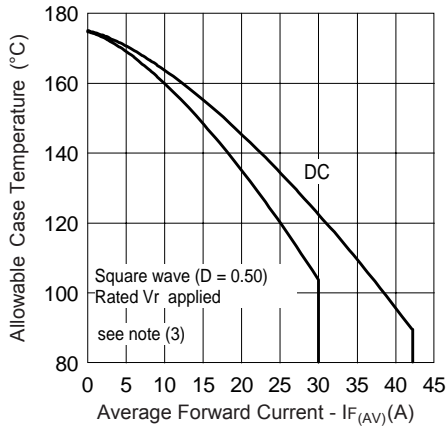
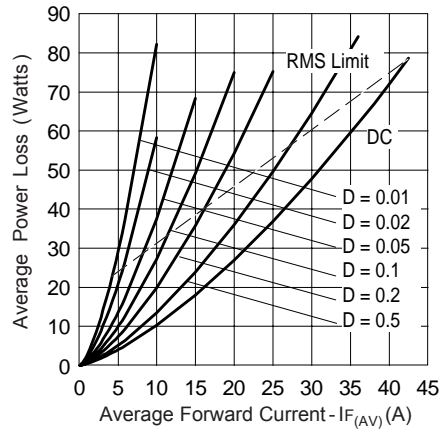


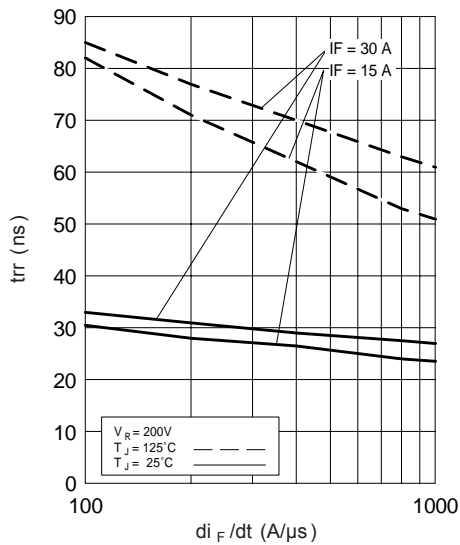
Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics



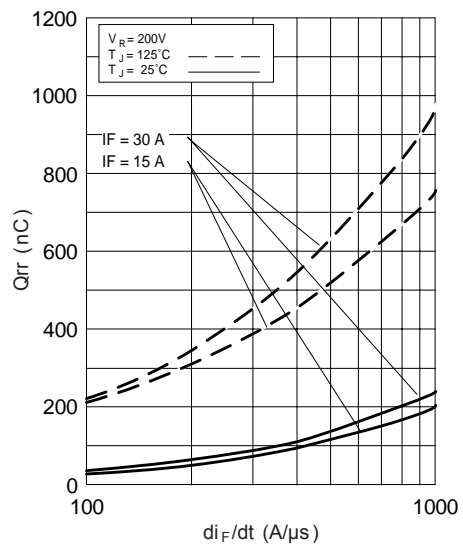
**Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current**



**Fig. 6 - Forward Power Loss Characteristics**



**Fig. 7 - Typical Reverse Recovery vs.  $di_F/dt$**



**Fig. 8 - Typical Stored Charge vs.  $di_F/dt$**

- (3) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  
 $Pd = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$  (see Fig. 6);  
 $Pd_{REV} = \text{Inverse Power Loss} = V_{R1} \times I_{R1} (1 - D)$ ;  $I_{R1} @ V_{R1} = \text{rated } V_R$

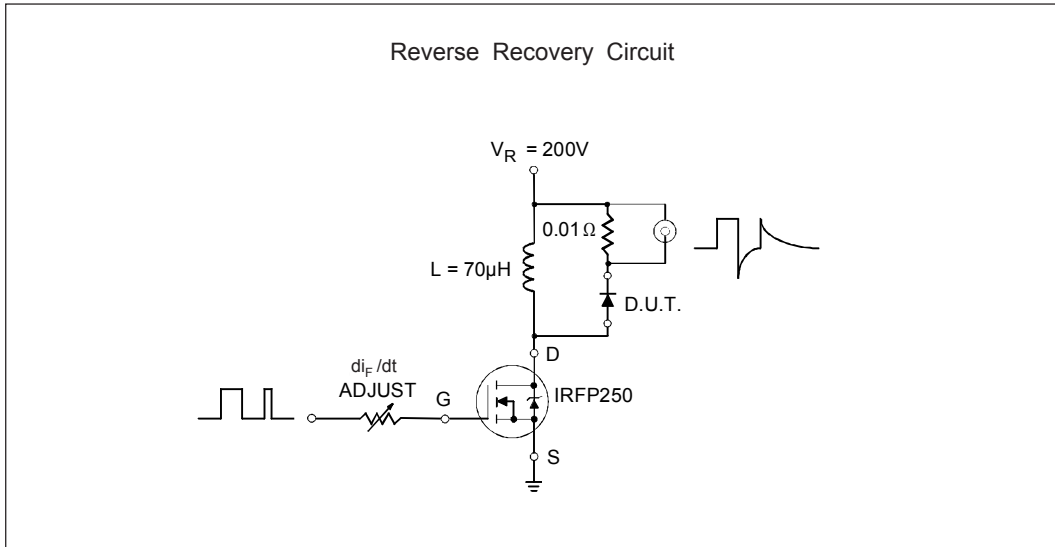


Fig. 9- Reverse Recovery Parameter Test Circuit

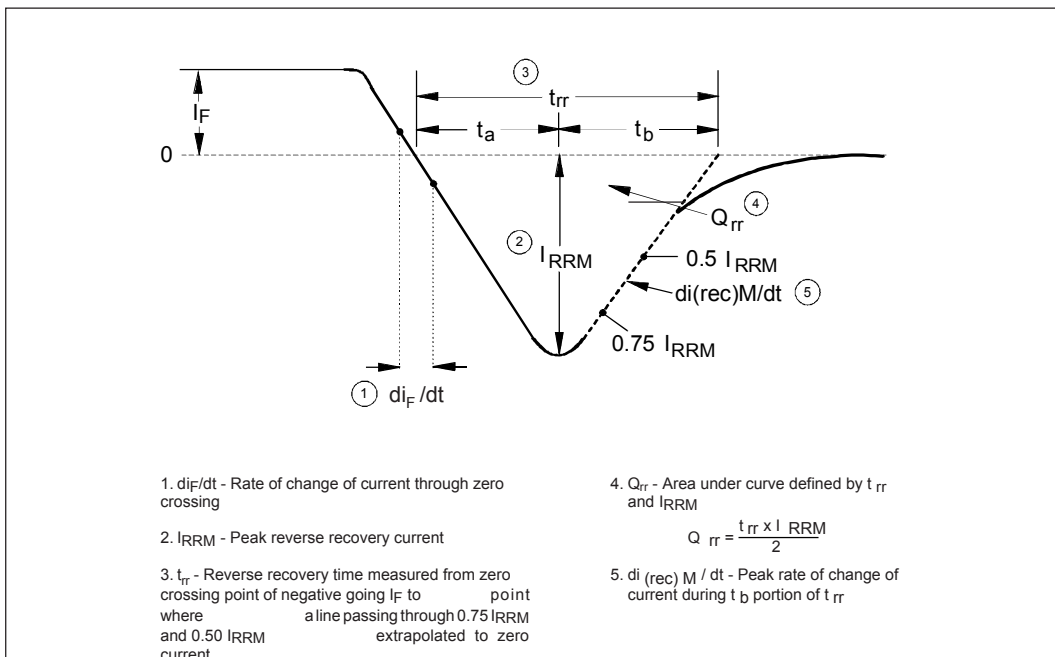
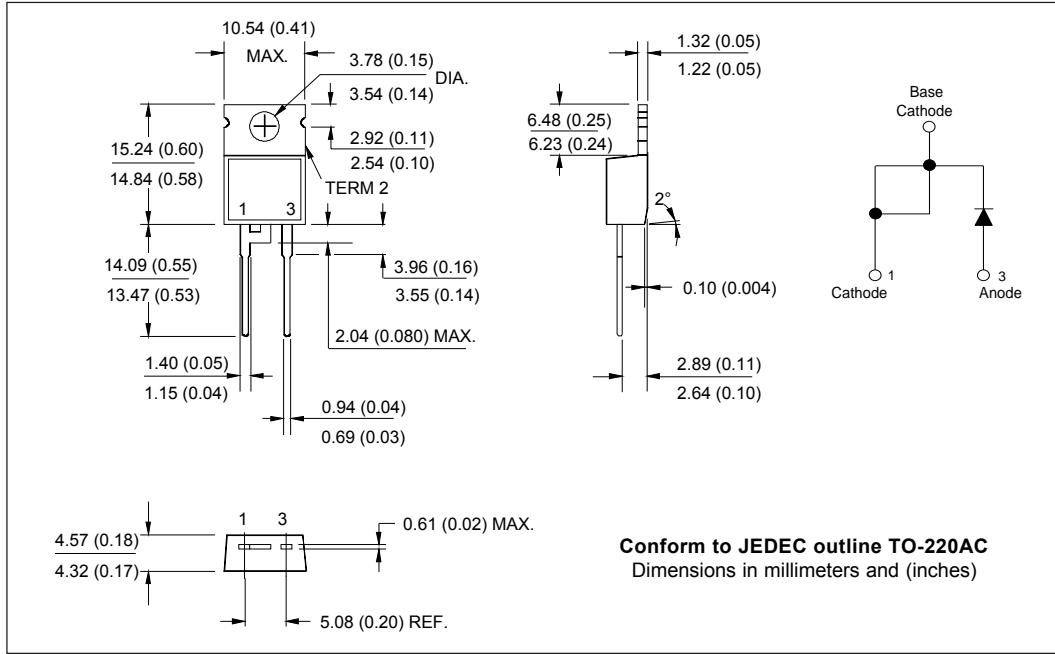
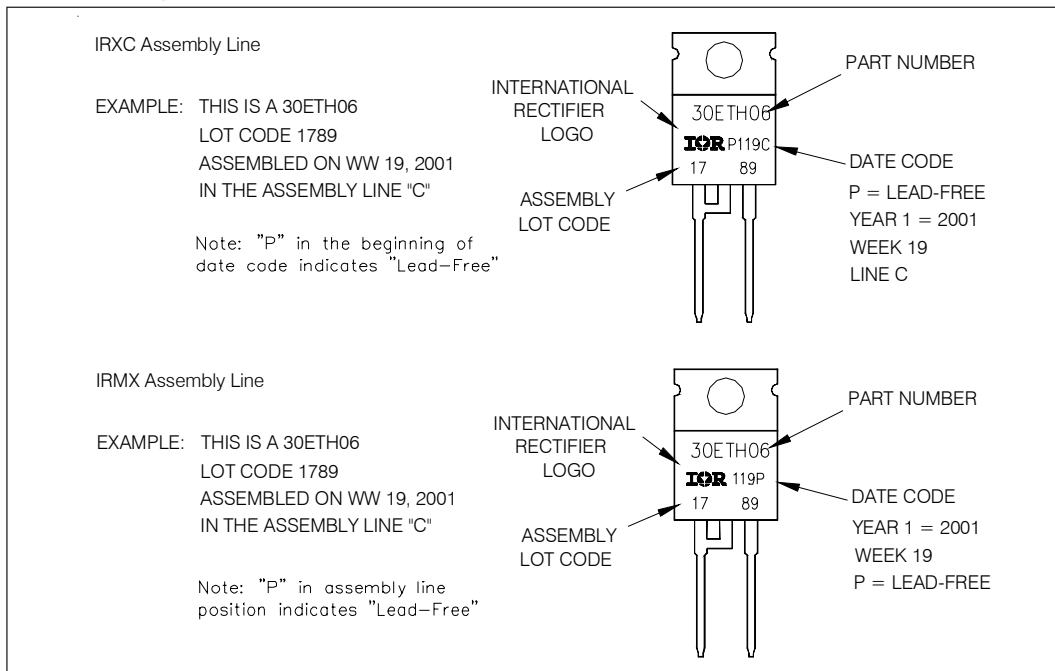


Fig. 10 - Reverse Recovery Waveform and Definitions

Outline Table



Part Marking Information



Ordering Information Table

Device Code													
	<table border="1" style="margin: auto;"> <tr> <td style="padding: 5px;">30</td> <td style="padding: 5px;">E</td> <td style="padding: 5px;">T</td> <td style="padding: 5px;">H</td> <td style="padding: 5px;">06</td> <td style="padding: 5px;">PbF</td> </tr> <tr> <td style="text-align: center;">①</td> <td style="text-align: center;">②</td> <td style="text-align: center;">③</td> <td style="text-align: center;">④</td> <td style="text-align: center;">⑤</td> <td style="text-align: center;">⑥</td> </tr> </table>	30	E	T	H	06	PbF	①	②	③	④	⑤	⑥
30	E	T	H	06	PbF								
①	②	③	④	⑤	⑥								
<b>1</b>	- Current Rating (30 = 30A)												
<b>2</b>	- E = Single Diode												
<b>3</b>	- Package T = TO-220												
<b>4</b>	- H = HyperFast Recovery												
<b>5</b>	- Voltage Rating (06 = 600V)												
<b>6</b>	- • none = Standard Production • PbF = Lead-Free												
Tube Standard Pack Quantity : 50 pieces													

Data and specifications subject to change without notice.  
 This product has been designed and qualified for Industrial Level and Lead-Free.  
 Qualification Standards can be found on IR's Web site.